

Device Modeling Report

COMPONENTS: BRT
PART NUMBER: RN1317
MANUFACTURER: TOSHIBA

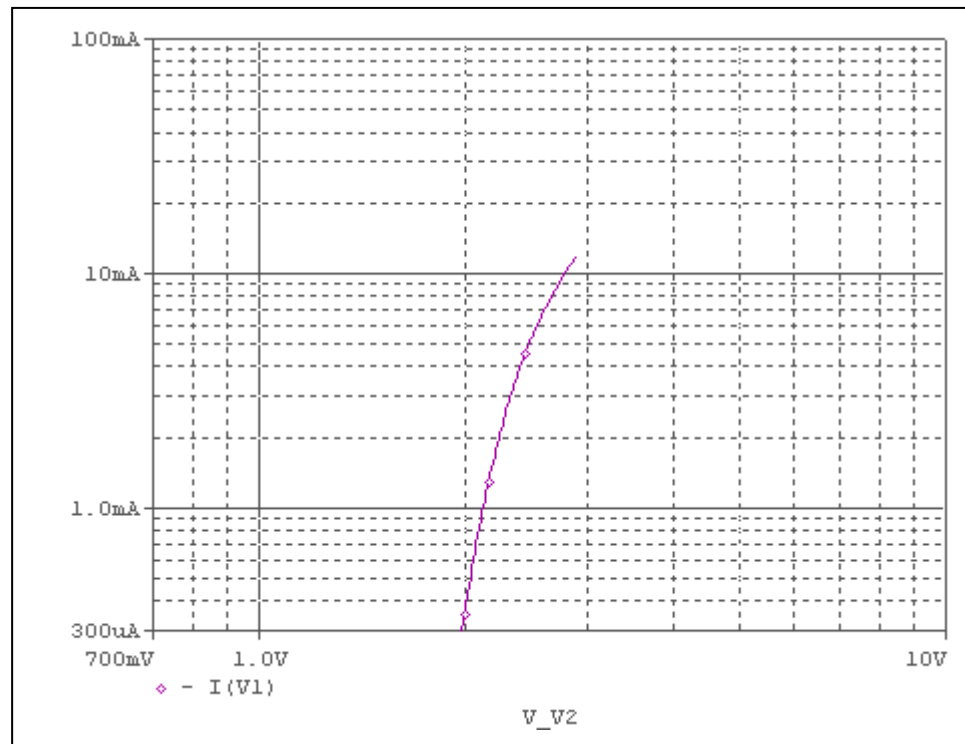


Bee Technologies Inc.

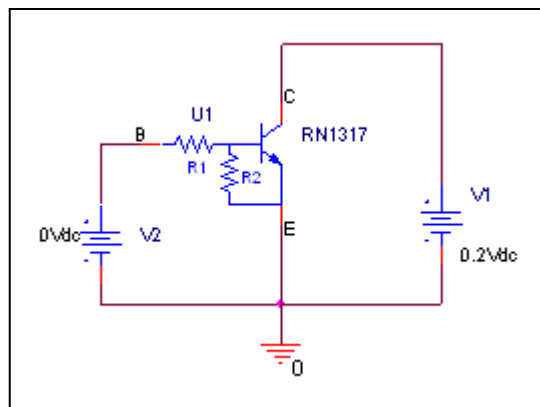
PSpice model parameter	Model description
IS	Saturation Current
BF	Ideal Maximum Forward Beta
NF	Forward Current Emission Coefficient
VAF	Forward Early Voltage
IKF	Forward Beta Roll-off Knee Current
ISE	Non-ideal Base-Emitter Diode Saturation Current
NE	Non-ideal Base-Emitter Diode Emission Coefficient
BR	Ideal Maximum Reverse Beta
NR	Reverse Emission Coefficient
VAR	Reverse Early Voltage
IKR	Reverse Beta Roll-off Knee Current
ISC	Non-ideal Base-Collector Diode Saturation Current
NC	Non-ideal Base-Collector Diode Emission Coefficient
NK	Forward Beta Roll-off Slope Exponent
RE	Emitter Resistance
RB	Base Resistance
RC	Series Collector Resistance
CJE	Zero-bias Emitter-Base Junction Capacitance
VJE	Emitter-Base Junction Potential
MJE	Emitter-Base Junction Grading Coefficient
CJC	Zero-bias Collector-Base Junction Capacitance
VJC	Collector-base Junction Potential
MJC	Collector-base Junction Grading Coefficient
FC	Coefficient for Onset of Forward-bias Depletion Capacitance
TF	Forward Transit Time
XTF	Coefficient for TF Dependency on Vce
VTF	Voltage for TF Dependency on Vce
ITF	Current for TF Dependency on Ic
PTF	Excess Phase at $f=1/2\pi \cdot TF$
TR	Reverse Transit Time
EG	Activation Energy
XTB	Forward Beta Temperature Coefficient
XTI	Temperature Coefficient for IS

Input voltage vs. output current (ON characteristics)

Circuit simulation result

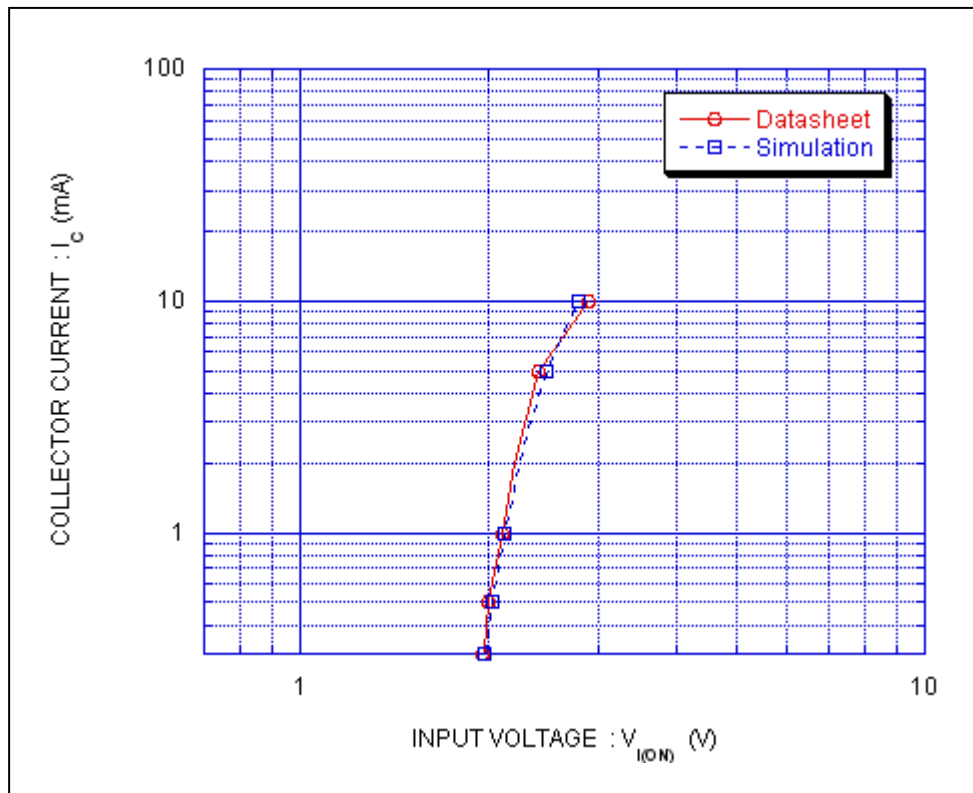


Evaluation circuit



Comparison Graph

Circuit Simulation Result



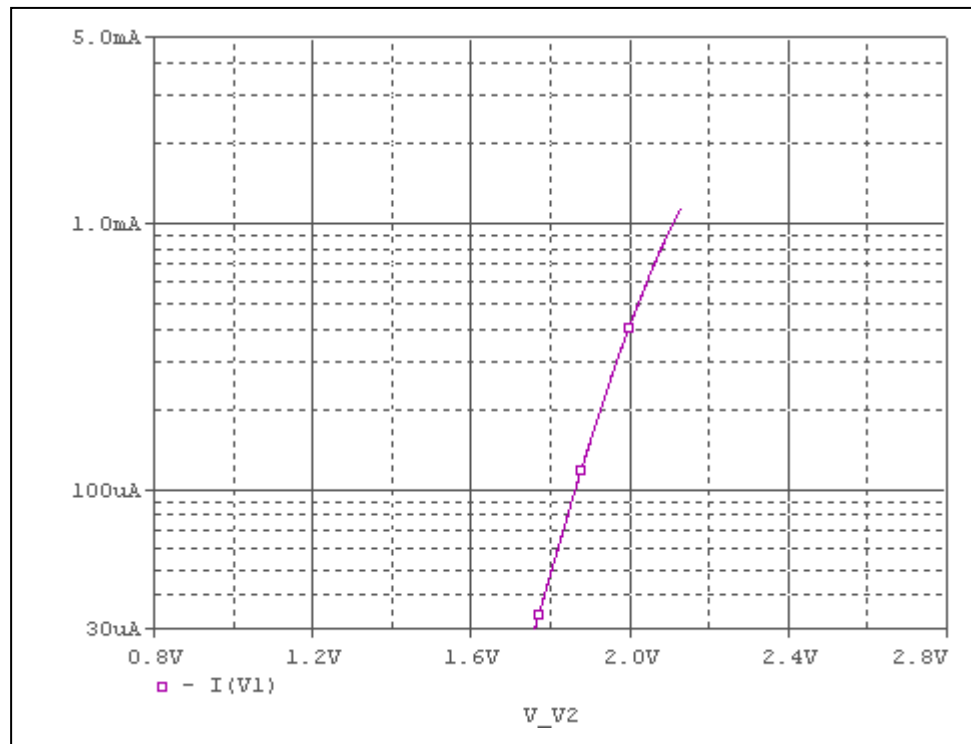
Simulation Result

Condition @ $V_{ce} = 0.2$ V

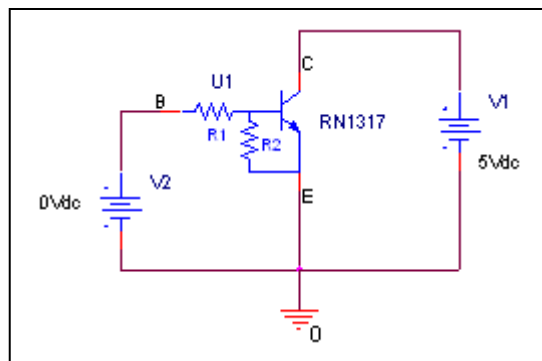
I_c (mA)	$V_{I(ON)}$ (V)		Error (%)
	Datasheet	Simulation	
0.3	1.95	1.9718	1.1179
0.5	2.0	2.0271	1.3550
1	2.1	2.1185	0.8810
2	2.2	2.2354	1.6091
5	2.4	2.4748	3.1167
10	2.9	2.7859	-3.9345

Output current vs. input voltage (OFF characteristics)

Circuit simulation result

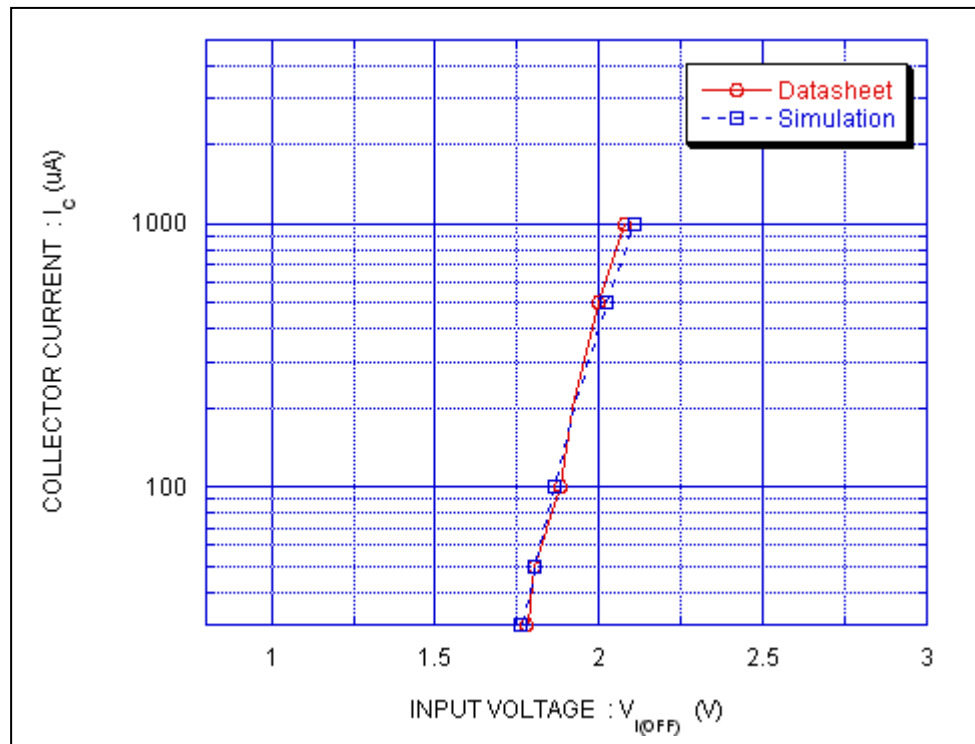


Evaluation circuit



Comparison Graph

Circuit Simulation Result



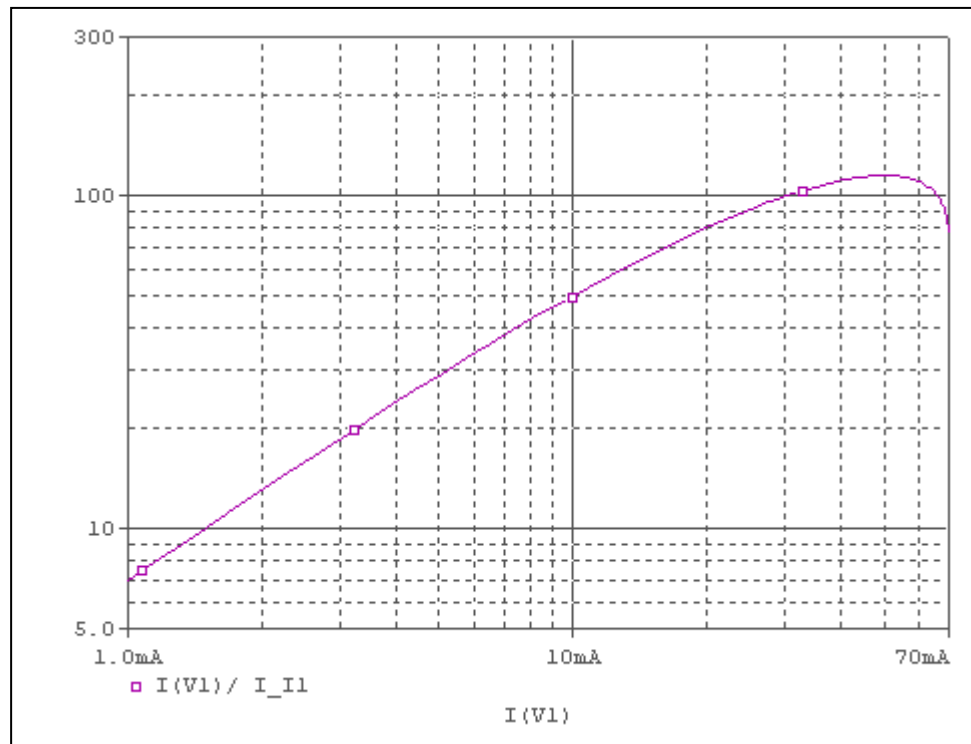
Simulation Result

Condition @ $V_{ce} = 5$ V

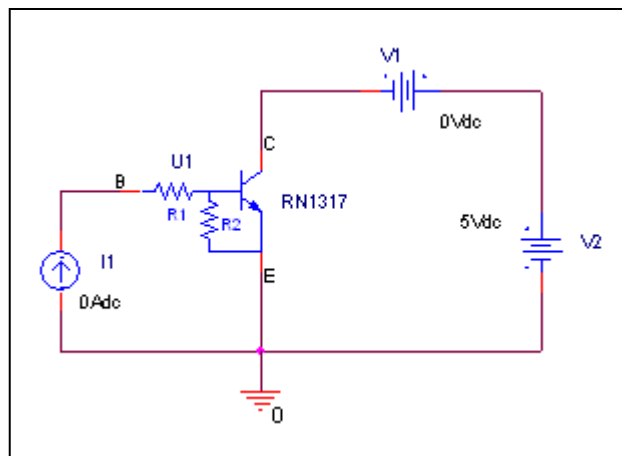
Ic(uA)	V _{I(Off)} (V)		Error (%)
	Datasheet	Simulation	
30	1.78	1.7610	-1.0674
50	1.8	1.8031	0.1722
100	1.88	1.8632	-0.8936
200	1.92	1.9272	0.3750
500	2.0	2.0237	1.1850
1000	2.08	2.1081	1.3510

DC current gain vs. output current

Circuit simulation result

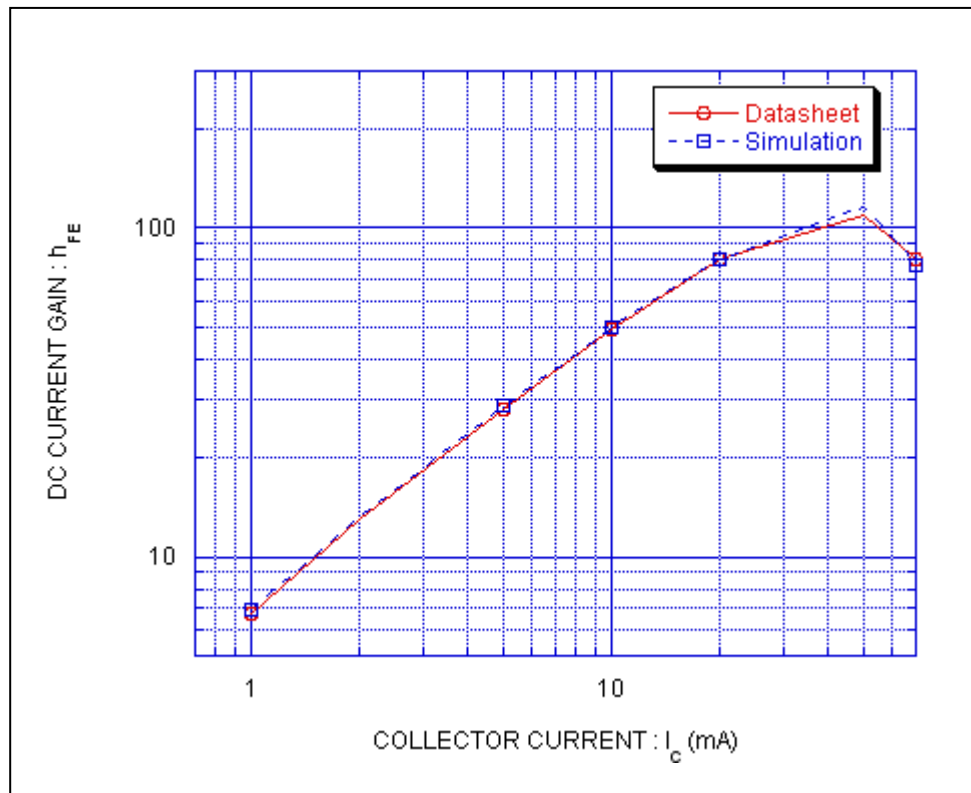


Evaluation circuit



Comparison Graph

Circuit Simulation Result



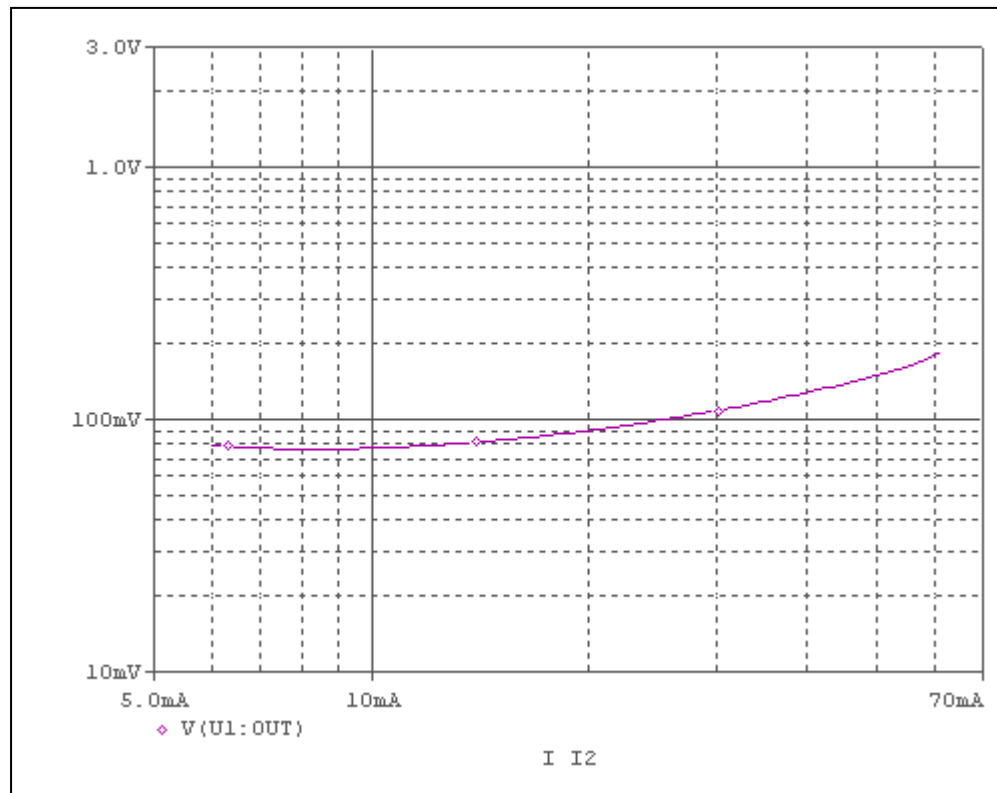
Simulation Result

Condition @ $V_{ce} = 5\text{ V}$

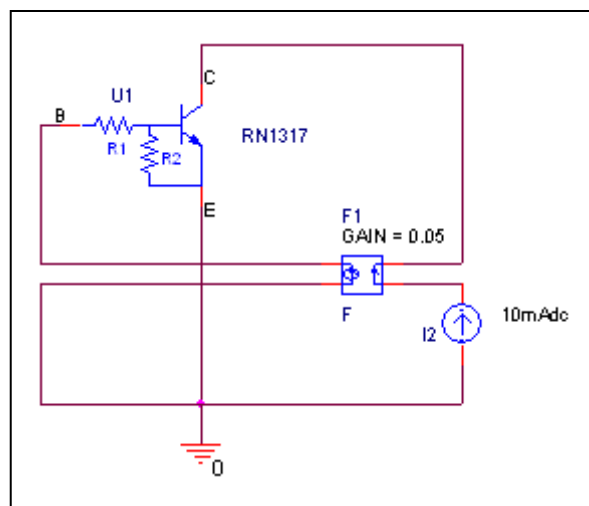
Ic(mA)	hFE		Error (%)
	Datasheet	Simulation	
1	6.7	6.9537	3.7866
2	13	13.078	0.6000
5	28	28.859	3.0679
10	49	50.060	2.1633
20	80	80.179	0.2238
50	110	114.929	4.4809
70	80	76.587	-4.2663

Output voltage VS. output current

Circuit simulation result

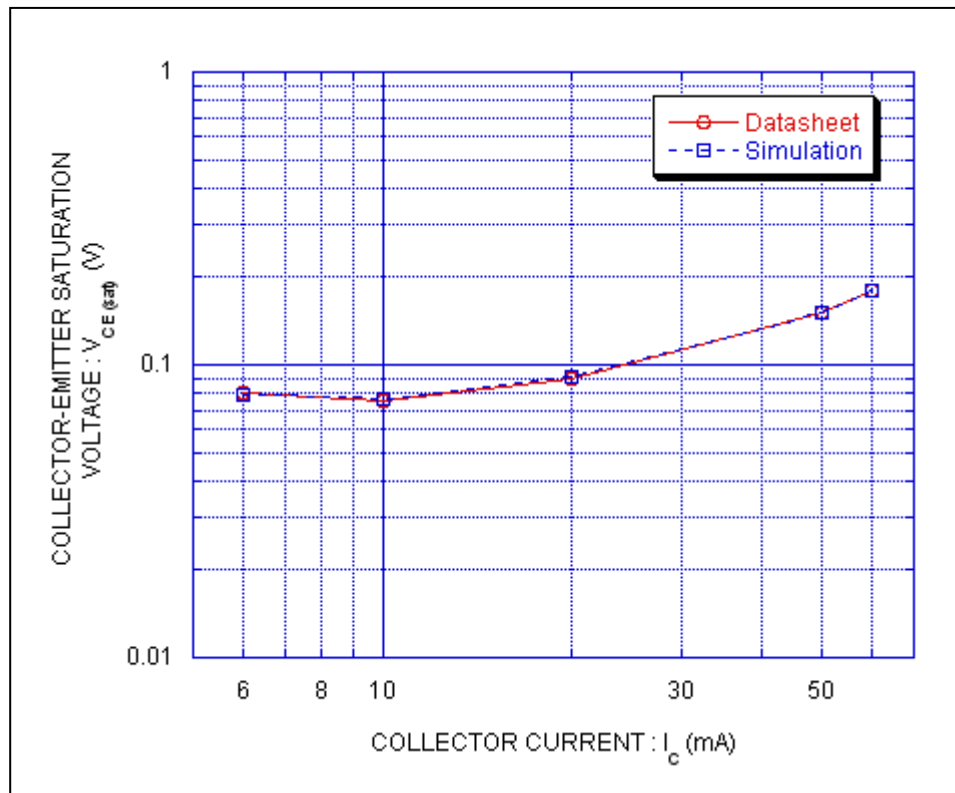


Evaluation circuit



Comparison Graph

Circuit Simulation Result



Simulation Result

Condition @ $I_C/I_B = 20$

Ic(mA)	V _{CE} (sat) (mV)		Error (%)
	Datasheet	Simulation	
6	0.08	0.079054	-1.1825
10	0.075	0.076951	2.6013
20	0.089	0.090569	1.7629
50	0.15	0.149860	-0.0933
60	0.18	0.178624	-0.7644